IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Previously Presented) A lithographic apparatus comprising:

an illumination system that provides a beam of radiation;

a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate;

a projection system that projects the patterned beam onto a target portion of the substrate; and

a debris-mitigation system that mitigates debris particles which are formed during use of at least a part of the lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, wherein the debris-mitigation system is further arranged to switch the magnetic field alternatingly on and off, and wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles, a current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.

- 2. (Original) A lithographic apparatus according to claim 1, wherein the debrismitigation system comprises a plurality of debris-trapping surfaces.
- 3. (Original) A lithographic apparatus according to claim 2, wherein the debrismitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.

- 4. (Original) A lithographic apparatus according to claim 1, wherein the debrismitigation system is further arranged to apply the magnetic field such that, in use, at least some of the charged debris particles spiralize.
- 5. (Original) A lithographic apparatus according to claim 1, wherein the debrismitigation system comprises at least one solenoid for applying the magnetic field.
 - 6. (Cancelled).
 - 7. (Cancelled).
 - 8. (Cancelled).
- 9. (Original) A lithographic apparatus according to claim 1, wherein the debrismitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
 - 10. (Cancelled).
- 11. (Currently Amended) A debris-mitigation system for mitigating debris particles within a lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, and wherein the debris-mitigation system is further arranged to apply a gradient to the magnetic field to create a volume in which the charged debris particles are substantially contained.
- 12. (Original) A debris-mitigation system according to claim 11, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.

- 13. (Original) A debris-mitigation system according to claim 12, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debristrapping surfaces.
- 14. (Original) A debris-mitigation system according to claim 11, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
 - 15. (Cancelled).
 - 16. (Cancelled).
- 17. (Previously Presented) A debris-mitigation system according to claim 11, wherein the debris-mitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency to create the gradient.
- 18. (Original) A debris-mitigation system according to claim 11, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
- 19. (Original) A debris-mitigation system according to claim 11, wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles an electric current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.

- 20. (Previously Presented) A source for producing EUV radiation, comprising a debris-mitigation system that mitigates debris particles which are formed during production of EUV radiation, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, and wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles an electric current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.
- 21. (Original) A source according to claim 20, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.
- 22. (Previously Presented) A source according to claim 21, wherein the debrismitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.
- 23. (Original) A source according to claim 20, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 24. (Original) A source according to claim 20, wherein the debris-mitigation system is further arranged to switch the magnetic field alternatingly on and off.
- 25. (Original) A source according to claim 20, wherein the debris-mitigation system is further arranged to apply a gradient to the magnetic field.
- 26. (Original) A source according to claim 20, wherein the debris-mitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency.

27. (Original) A source for producing EUV radiation according to claim 20, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.

28. (Cancelled).

29. (Currently Amended) A method for mitigating debris as produced during use of at least a part of a lithographic apparatus, the method comprising:

applying a magnetic field so that at least charged debris particles are mitigated; and applying a gradient to the magnetic field to create a volume in which the charged debris particles are substantially contained.

- 30. (Original) A method according to claim 29, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.
- 31. (Original) A method according to claim 30, wherein the magnetic field is applied such that, in use, the charged particles are moved substantially towards at least one of the number of debris-trapping surfaces.
- 32. (Original) A method according to claim 29, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 33. (Original) A method according to claim 29, wherein the magnetic field is alternatingly switched on and off.
 - 34. (Cancelled).

35. (Previously Presented) A method according to claim 29, wherein the magnetic field is applied dynamically with a predetermined frequency to create the gradient.

36. (Original) A method according to claim 29, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.

37. (Original) A method according to claim 29, wherein within a group of the desired particles an external electric current is induced such that at least charged debris particles deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current externally induced.

- 38. (Cancelled).
- 39. (Cancelled).
- 40. (Cancelled).
- 41. (Currently Amended) A lithographic method comprising:

generating a beam of EUV radiation, wherein production of said EUV radiation causes generation of charged particle debris as a byproduct;

patterning said beam of EUV radiation;

projecting said patterned beam of EUV radiation onto a substrate;

generating a magnetic field to interact with said charged debris particles; and

applying a gradient to the magnetic field to create a volume in which the charged debris particles are substantially contained.

42. (Currently Amended) A lithographic apparatus comprising:

an illumination system that provides a beam of radiation;

a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate;

a projection system that projects the patterned beam onto a target portion of the substrate; and

a debris-mitigation system that mitigates debris particles which are formed during use of at least a part of the lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, and wherein the debris-mitigation system is further arranged to apply a gradient to the magnetic field to create a volume in which the charged debris particles are substantially contained.

- 43. (Previously Presented) A lithographic apparatus according to claim 42, wherein the debris-mitigation system comprises a plurality of debris-trapping surfaces.
- 44. (Previously Presented) A lithographic apparatus according to claim 43, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.
- 45. (Previously Presented) A lithographic apparatus according to claim 42, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, at least some of the charged debris particles spiralize.

- 46. (Previously Presented) A lithographic apparatus according to claim 42, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 47. (Previously Presented) A lithographic apparatus according to claim 42, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
 - 48. (Currently Amended) A lithographic apparatus comprising:

an illumination system that provides a beam of radiation;

a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

a substrate support that supports a substrate;

a projection system that projects the patterned beam onto a target portion of the substrate; and

a debris-mitigation system that mitigates debris particles which are formed during use of at least a part of the lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, and wherein the debris-mitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency to create a volume in which the charged debris particles are substantially contained.

- 49. (Previously Presented) A lithographic apparatus according to claim 48, wherein the debris-mitigation system comprises a plurality of debris-trapping surfaces.
- 50. (Previously Presented) A lithographic apparatus according to claim 49, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.

- 51. (Previously Presented) A lithographic apparatus according to claim 48, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, at least some of the charged debris particles spiralize.
- 52. (Previously Presented) A lithographic apparatus according to claim 48, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 53. (Previously Presented) A lithographic apparatus according to claim 48, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
 - 54. (Previously Presented) A lithographic apparatus comprising: an illumination system that provides a beam of radiation;
- a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;
 - a substrate support that supports a substrate;
- a projection system that projects the patterned beam onto a target portion of the substrate; and

a debris-mitigation system that mitigates debris particles which are formed during use of at least a part of the lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated, wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles an electric current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.

- 55. (Previously Presented) A lithographic apparatus according to claim 54, wherein the debris-mitigation system comprises a plurality of debris-trapping surfaces.
- 56. (Previously Presented) A lithographic apparatus according to claim 55, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.
- 57. (Previously Presented) A lithographic apparatus according to claim 54, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, at least some of the charged debris particles spiralize.
- 58. (Previously Presented) A lithographic apparatus according to claim 54, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 59. (Previously Presented) A lithographic apparatus according to claim 54, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
- 60. (New) A debris-mitigation system according to claim 11, wherein the debris-mitigation system is further arranged to allow at least some of the charged debris particles to escape from the volume.
- 61. (New) A method according to claim 29, wherein the magnetic field is applied such that at least some of the charged debris particles escape from the volume.

- 62. (New) A lithographic method according to claim 41, wherein the magnetic field is applied such that at least some of the charged debris particles escape from the volume.
- 63. (New) A lithographic apparatus according to claim 42, wherein the debrismitigation system is further arranged to allow at least some of the charged debris particles to escape from the volume.
- 64. (New) A lithographic apparatus according to claim 48, wherein the debrismitigation system is further arranged to allow at least some of the charged debris particles to escape from the volume.